High Speed Real-time Temperature Monitoring System inside Power Devices Package Using Infrared Radiation

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High Speed Real-time Temperature Monitoring System inside Power Devices Package Using Infrared Radiation

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Abstract

We proposed high speed real-time temperature monitoring system using infrared radiation in order to analyse thermal behaviour inside power device packages. This system was able to monitor thermal distribution in the package and confirmed thermal transition in this area with time resolution of 10 ms and special resolution of 15μm. Accuracy of the measured temperature of each material with different infrared emissivity in the package was ensured by calibration obtained experimentally.

1. Introduction

The complexity of the internal structure and the miniaturization of power devices are increased thermal density in the package. In order to ensure the reliability of power devices, therefore, it is necessary to analyze the thermal behavior in the packages and to consider proper thermal design. Experimental verification is also essential in addition to thermal simulation in the proper thermal design for power devices [1].

Temperature monitoring with infrared radiation is generally used by the way of non-contact method. However, it is difficult to monitor the accurate temperature distribution in the package because the emissivity is different by materials and it easily changes by irregularity in the surface or oxidation [2, 3, 4]. Although this problem is resolved by black spray paint, spatial resolution and time response to temperature transition is spoiled.

We propose a high speed temperature monitoring system to measure the thermal distribution in power device packages by using infrared radiation. Infrared radiance from each material inside the package was converted to accurate temperature by calibration curve obtained experimentally. This method did not spoil spatial and time resolution of measurement.

2. Infrared Measurement System

We used an infrared camera (FLIR SC7600) to measure the thermal distribution in this temperature measurement system (see Fig. 1). The frame rate of this camera is up to 3 kHz. In order to measure local area of a power semiconductor chip, slitting process was employed to expose semiconductor chip inside the package (see Fig. 2). In addition, we use the optical slit to cut off radiation except the slitting bottom (see Fig. 3). We also simultaneously measure the temperature of each material in the package by a fiber-optical thermometer to obtain accurate temperature carburation curves.

3. Measurement results

A TO-220AC packaged power diode with maximum rating of repetitive reverse voltage of 1200 V was prepared for this demonstration. Radiation from 1 mm width chip region monitored through a 0.8 mm width optical slit was shown in Fig. 4. This system acquired these images with time resolution of 10ms and spatial resolution of 15μm.

The radiance of the infrared camera measured from each material inside the package was converted to temper-
ature with relationship in Fig. 5. Although, the radiance indicated discontinuously at the interface between Si chip and Cu plate, the temperature distribution after calibration was kept continuously at each interface (Fig. 6).

![Infrared radiation image](image1)

![Calibration curve for each part of package](image2)

**Fig. 4 Infrared radiation image**

**Fig. 5 Calibration curve for each part of package**

**4. Conclusion**

Our proposed temperature monitoring system was successively measure the thermal distribution in the package of power devices. Original calibration method solved difficulty of conversion from infrared radiation data to accurate temperature value without spatial and time resolution of the monitoring.

**References**


